## 74LVC2G53 <br> 2-channel analog multiplexer/demultiplexer

Rev. 01 - 10 January 2006
Product data sheet

## 1. General description

The 74LVC2G53 is a high-performance, low-power, low-voltage, Si-gate CMOS device that provides superior performance to most advanced CMOS compatible TTL families.

The 74LVC2G53 provides one analog multiplexer/demultiplexer with a digital select input $(\mathrm{S})$, two independent inputs/outputs ( B 0 and B 1 ), a common input/output ( A ) and an active LOW enable input $(\overline{\mathrm{E}})$. When pin $\overline{\mathrm{E}}$ is HIGH, the switch is turned off.

The 74LVC2G53 can handle both analog and digital signals.

## 2. Features

■ Wide supply voltage range from 1.65 V to 5.5 V

- Very low ON resistance:
-7.5 $\Omega$ (typical) at $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$
-6.5 $\Omega$ (typical) at $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$
- $6 \Omega$ (typical) at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$
- High noise immunity
- ESD protection:
- HBM JESD22-A114-C exceeds 2000 V
- MM JESD22-A115-A exceeds 200 V
- CDM JESD22-C101-C exceeds 1000 V
- CMOS low-power consumption
- Latch-up performance meets requirements of JESD 78 Class I
- Direct interface with TTL levels
- Control inputs accepts voltages up to 5 V
- Multiple package options
- Specified from $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ and from $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$


## 3. Quick reference data

Table 1: Quick reference data
$G N D=0 \mathrm{~V} ; t_{r}=t_{f} \leq 2.5 \mathrm{~ns}$; minimum and maximum values at $T_{\text {amb }}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$;
typical values at $T_{a m b}=25^{\circ} \mathrm{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {on }}$ | turn-on time |  |  |  |  |  |
|  | S to A or Bn | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} ; \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$ | 1.8 | 3.4 | 5.0 | ns |
|  |  | $\mathrm{V}_{C C}=5.0 \mathrm{~V}$ | 1.3 | 2.6 | 3.8 | ns |
|  | $\bar{E}$ to A or Bn | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} ; \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  |  |  |  |
|  |  | $\mathrm{V}_{C C}=3.3 \mathrm{~V}$ | 1.2 | 2.2 | 3.8 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ | 1.0 | 1.7 | 2.6 | ns |
| $\mathrm{t}_{\text {off }}$ | turn-off time |  |  |  |  |  |
|  | S to A or Bn | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} ; \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  |  |  |  |
|  |  | $\mathrm{V}_{C C}=3.3 \mathrm{~V}$ | 1.1 | 4.0 | 5.4 | ns |
|  |  | $\mathrm{V}_{C C}=5.0 \mathrm{~V}$ | 1.0 | 2.9 | 3.8 | ns |
|  | $\overline{\mathrm{E}}$ to A or Bn | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} ; \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  |  |  |  |
|  |  | $\mathrm{V}_{C C}=3.3 \mathrm{~V}$ | 2.0 | 3.7 | 5.0 | ns |
|  |  | $\mathrm{V}_{C C}=5.0 \mathrm{~V}$ | 1.3 | 2.9 | 3.8 | ns |
| $\mathrm{Ci}_{i}$ | input capacitance |  | - | 2.5 | - | pF |
| $\mathrm{C}_{\text {S(OFF) }}$ | OFF-state capacitance |  | - | 6.0 | - | pF |
| $\mathrm{C}_{\text {S(ON) }}$ | ON-state capacitance |  | - | 18 | - | pF |

## 4. Ordering information

Table 2: Ordering information

| Type number | Package |  |  |  |
| :--- | :--- | :--- | :--- | :--- |
|  | Temperature range | Name | Description | Version |
| 74LVC2G53DC | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | VSSOP8 | plastic very thin shrink small <br> outline package; 8 leads; <br> body width 2.3 mm | SOT765-1 |

## 5. Marking

Table 3: Marking

| Type number | Marking code |
| :--- | :--- |
| 74LVC2G53DC | V53 |
| 74LVC2G53GT | V53 |

## 6. Functional diagram



Fig 1. Logic symbol


Fig 2. Logic diagram

## 7. Pinning information

### 7.1 Pinning



Fig 3. Pin configuration VSSOP8


Fig 4. Pin configuration XSON8

### 7.2 Pin description

Table 4: Pin description

| Symbol | Pin | Description |
| :--- | :--- | :--- |
| A | 1 | common A output or input |
| $\overline{\mathrm{E}}$ | 2 | enable input (active LOW) |
| GND | 3 | ground $(0 \mathrm{~V})$ |
| GND | 4 | ground $(0 \mathrm{~V})$ |
| S | 5 | select input |
| B1 | 6 | independent B1 input or output |
| B0 | 7 | independent B0 input or output |
| $\mathrm{V}_{\mathrm{CC}}$ | 8 | supply voltage |

## 8. Functional description

### 8.1 Function table

Table 5: Function table [1]

| Input |  | Channel on |
| :--- | :--- | :--- |
| S | E |  |
| L | L | B0 to A or A to B0 |
| H | L | B1 to A or A to B1 |
| X | H | Z (switch off) |
| $[1]$ | H $=$ HIGH voltage level; |  |
|  | L $=$ LOW voltage level; |  |
|  | X $=$ don't care; |  |
|  | Z | $=$ high-impedance OFF-state. |

## 9. Limiting values

Table 6: Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).
Voltages are referenced to GND (ground $=0 \mathrm{~V}$ ).

| Symbol | Parameter | Conditions | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{C C}$ | supply voltage |  | -0.5 | +6.5 | V |
| V | input voltage |  | [1] -0.5 | +6.5 | V |
| $\mathrm{I}_{\mathrm{K}}$ | input clamping current | $\mathrm{V}_{1}<-0.5 \mathrm{~V}$ or $\mathrm{V}_{1}>\mathrm{V}_{C C}+0.5$ | - | -50 | mA |
| $\mathrm{I}_{\text {SK }}$ | switch clamping current | $\mathrm{V}_{1}<-0.5 \mathrm{~V}$ or $\mathrm{V}_{1}>\mathrm{V}_{\mathrm{CC}}+0.5$ | - | $\pm 50$ | mA |
| $\mathrm{V}_{\text {SW }}$ | switch voltage | enable and disable mode | -0.5 | $\mathrm{V}_{\mathrm{CC}}+0.5$ | V |
| ISw | switch current | $\mathrm{V}_{\mathrm{SW}}=-0.5 \mathrm{~V}$ to $\left(\mathrm{V}_{\mathrm{CC}}+0.5 \mathrm{~V}\right)$ | - | $\pm 50$ | mA |
| ICC | quiescent supply current |  | - | 100 | mA |
| $\mathrm{I}_{\text {GND }}$ | ground current |  | - | -100 | mA |
| $\mathrm{T}_{\text {stg }}$ | storage temperature |  | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{P}_{\text {tot }}$ | total power dissipation | $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | [2] - | 300 | mW |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
[2] For VSSOP8 package: above $110^{\circ} \mathrm{C}$ the value of $\mathrm{P}_{\text {tot }}$ derates linearly with $8 \mathrm{~mW} / \mathrm{K}$. For XSON8 package: above $45^{\circ} \mathrm{C}$ the value of $\mathrm{P}_{\text {tot }}$ derates linearly with $2.4 \mathrm{~mW} / \mathrm{K}$.

## 10. Recommended operating conditions

Table 7: Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{V}_{\mathrm{CC}}$ | supply voltage |  | 1.65 | - | 5.5 | V |
| $\mathrm{~V}_{\mathrm{I}}$ | input voltage |  | 0 | - | 5.5 | V |
| $\mathrm{~V}_{\mathrm{SW}}$ | switch voltage | enable and disable <br> mode | [1] 0 | - | $\mathrm{V}_{\mathrm{CC}}$ | V |
|  |  |  | -40 | - | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{amb}}$ | ambient temperature |  |  |  |  |  |
| $\Delta \mathrm{t} / \Delta \mathrm{V}$ | input transition rise and <br> fall rate | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 2.7 V | [2] | 0 | - | 20 |
| n | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ to 5.5 V | [2] | 0 | - | 10 | $\mathrm{~ns} / \mathrm{V}$ |

[^0]
## 11. Static characteristics

Table 8: Static characteristics
At recommended operating conditions; voltages are referenced to GND (ground 0 V ).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C} \underline{[1]}$ |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IH}}$ | HIGH-state input voltage | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | $0.65 \mathrm{~V}_{\text {cc }}$ | - | - | V |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ to 2.7 V | 1.7 | - | - | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | 2.0 | - | - | V |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$ to 5.5 V | $0.7 \mathrm{~V}_{\mathrm{CC}}$ | - | - | V |
| $\mathrm{V}_{\text {IL }}$ | LOW-state input voltage | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | - | - | $0.35 \mathrm{~V}_{\text {cc }}$ | V |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ to 2.7 V | - | - | 0.7 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | - | 0.8 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | - | $0.3 \mathrm{~V}_{\text {cc }}$ | V |
| $l_{\text {LI }}$ | input leakage current | on pin $S$ and pin $\bar{E}$; $\mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V} \text { or GND; } \mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | - | $\pm 0.1$ | $\pm 2$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {S(OFF) }}$ | OFF-state leakage current | per channel; <br> $V_{S W}=G N D$ and $V_{O}=V_{C C}$ <br> or $\mathrm{V}_{\mathrm{SW}}=\mathrm{V}_{\mathrm{CC}}$ and $\mathrm{V}_{\mathrm{O}}=\mathrm{GND}$; <br> $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$; see Figure 5 | - | $\pm 0.1$ | $\pm 5$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {(ON })}$ | ON-state leakage current | per channel; <br> $\mathrm{V}_{\mathrm{SW}}=\mathrm{GND}$ or $\mathrm{V}_{\mathrm{CC}} ; \mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$; <br> see Figure 6 | - | $\pm 0.1$ | $\pm 5$ | $\mu \mathrm{A}$ |
| $I_{\text {cc }}$ | quiescent supply current | $\begin{aligned} & \mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{CC}} \text { or } \mathrm{GND} ; \\ & \mathrm{V}_{\mathrm{SW}}=\mathrm{GND} \text { or } \mathrm{V}_{\mathrm{CC}} ; \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} ; \\ & \mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V} \end{aligned}$ | - | 0.1 | 10 | $\mu \mathrm{A}$ |
| $\Delta \mathrm{l}_{\text {CC }}$ | additional quiescent supply current | per input pin; $\begin{aligned} & \mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{CC}}-0.6 \mathrm{~V} ; \mathrm{V}_{\mathrm{SW}}=\mathrm{GND} \text { or } \mathrm{V}_{\mathrm{CC}} \\ & \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} ; \mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V} \end{aligned}$ | - | 5 | 500 | $\mu \mathrm{A}$ |
| $\mathrm{C}_{\mathrm{i}}$ | input capacitance |  | - | 2.5 | - | pF |
| $\mathrm{C}_{\text {S(OFF) }}$ | OFF-state capacitance |  | - | 6.0 | - | pF |
| $\mathrm{C}_{\text {S(ON) }}$ | ON-state capacitance |  | - | 18 | - | pF |
| $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{IH}}$ | HIGH-state input voltage | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | $0.65 \mathrm{~V}_{\text {cc }}$ | - | - | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | 1.7 | - | - | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | 2.0 | - | - | V |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$ to 5.5 V | $0.7 \mathrm{~V}_{\mathrm{CC}}$ | - | - | V |
| $\mathrm{V}_{\text {IL }}$ | LOW-state input voltage | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | - | - | $0.35 V_{\text {cc }}$ | V |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ to 2.7 V | - | - | 0.7 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | - | 0.8 | V |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$ to 5.5 V |  | - | $0.3 \mathrm{~V}_{\mathrm{CC}}$ | V |
| $\mathrm{ILI}^{\prime}$ | input leakage current | on pin $S$ and pin $\bar{E}$; $\mathrm{V}_{\mathrm{I}}=5.5 \mathrm{~V} \text { or GND; } \mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | - | - | $\pm 10$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {S(OFF) }}$ | OFF-state leakage current | per channel; <br> $\mathrm{V}_{\mathrm{SW}}=\mathrm{GND}$ and $\mathrm{V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{CC}}$ <br> or $\mathrm{V}_{\mathrm{SW}}=\mathrm{V}_{\mathrm{CC}}$ and $\mathrm{V}_{\mathrm{O}}=\mathrm{GND}$; <br> $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$; see Figure 5 | - | - | $\pm 20$ | $\mu \mathrm{A}$ |

Table 8: Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\text {(ON })}$ | ON-state leakage current | per channel; <br> $\mathrm{V}_{\mathrm{SW}}=\mathrm{GND}$ or $\mathrm{V}_{\mathrm{CC}} ; \mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$; <br> see Figure 6 | - | - | $\pm 20$ | $\mu \mathrm{A}$ |
| ICC | quiescent supply current | $\begin{aligned} & \mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{CC}} \text { or } \mathrm{GND} ; \\ & \mathrm{V}_{\mathrm{SW}}=\mathrm{GND} \text { or } \mathrm{V}_{\mathrm{CC}} ; \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} ; \\ & \mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V} \end{aligned}$ | - | - | 40 | $\mu \mathrm{A}$ |
| $\Delta l_{\text {CC }}$ | additional quiescent supply current | per input pin; $\begin{aligned} & \mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{CC}}-0.6 \mathrm{~V} ; \mathrm{V}_{\mathrm{SW}}=\mathrm{GND} \text { or } \mathrm{V}_{\mathrm{CC}} ; \\ & \mathrm{I}_{\mathrm{O}}=0 \mathrm{~A} ; \mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V} \end{aligned}$ | - | - | 5000 | $\mu \mathrm{A}$ |

[1] Typical values are measured at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$.


Fig 5. Test circuit for measuring switch OFF-state current


| S | $\overline{\mathrm{E}}$ |
| :---: | :---: |
| $\mathrm{V}_{\mathrm{IL}}$ | $\mathrm{V}_{\mathrm{IL}}$ |
| $\mathrm{V}_{\mathrm{IH}}$ | $\mathrm{V}_{\mathrm{IL}}$ |

$V_{S W}=V_{C C}$ or GND.
Fig 6. Test circuit for measuring switch ON-state current

Table 9: Resistance $\mathbf{R}_{\text {on }}$
At recommended operating conditions; voltages are referenced to GND (ground = 0 V ); see test circuit Figure 7 .

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C} \underline{[1]}$ |  |  |  |  |  |  |
| $\mathrm{R}_{\mathrm{ON} \text { (rail) }}$ | ON resistance (rail) | $\mathrm{V}_{\text {SW }}=\mathrm{GND}$ |  |  |  |  |
|  |  | $\mathrm{I}_{\mathrm{SW}}=4 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V | - | 8.7 | 18 | $\Omega$ |
|  |  | $\mathrm{I}_{\text {SW }}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | 7.2 | 16 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | 7.0 | 14 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | 6.5 | 12 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=32 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | 5.9 | 10 | $\Omega$ |
|  |  | $\mathrm{V}_{\text {SW }}=\mathrm{V}_{\text {CC }}$ |  |  |  |  |
|  |  | $\mathrm{I}_{\mathrm{SW}}=4 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V | - | 12 | 30 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | 8.3 | 20 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | 7.8 | 18 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | 6.7 | 15 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=32 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | 5.2 | 10 | $\Omega$ |
| $\mathrm{R}_{\mathrm{ON} \text { (peak) }}$ | ON resistance (peak) | $\mathrm{V}_{\mathrm{SW}}=\mathrm{GND}$ to $\mathrm{V}_{\mathrm{CC}}$ |  |  |  |  |
|  |  | $\mathrm{I}_{\mathrm{SW}}=4 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V | - | 57 | 130 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | 15 | 30 | $\Omega$ |
|  |  | $\mathrm{I}_{\text {SW }}=12 \mathrm{~mA} ; \mathrm{V}_{\text {CC }}=2.7 \mathrm{~V}$ | - | 13 | 25 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | 9.0 | 20 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=32 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | 6.0 | 15 | $\Omega$ |
| $\mathrm{R}_{\mathrm{ON} \text { (flat) }}$ | ON resistance (flatness) | $\mathrm{V}_{\mathrm{SW}}=\mathrm{GND}$ to $\mathrm{V}_{\mathrm{CC}}$; see Figure 9 |  |  |  |  |
|  |  | $\mathrm{I}_{\mathrm{SW}}=4 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V | - | 100 | - | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | 17 | - | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | 10 | - | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | 5 | - | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=32 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | 3 | - | $\Omega$ |
| $\mathrm{T}_{\mathrm{amb}}=-40^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C}$ |  |  |  |  |  |  |
| $\mathrm{R}_{\mathrm{ON} \text { (rail) }}$ | ON resistance (rail) | $\mathrm{V}_{\mathrm{SW}}=\mathrm{GND}$ |  |  |  |  |
|  |  | $\mathrm{I}_{\mathrm{SW}}=4 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V | - | - | 27 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | - | 24 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | - | 21 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | - | 18 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=32 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | - | 15 | $\Omega$ |
|  |  | $\mathrm{V}_{\mathrm{SW}}=\mathrm{V}_{\mathrm{CC}}$ |  |  |  |  |
|  |  | $\mathrm{I}_{\mathrm{SW}}=4 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V | - | - | 45 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | - | 30 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | - | 27 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | - | 23 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=32 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | - | 15 | $\Omega$ |

Table 9: Resistance $\mathbf{R}_{\text {on }}$...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V ); see test circuit Figure 7.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $R_{\mathrm{ON}(\text { peak })}$ | ON resistance (peak) | $\mathrm{V}_{\mathrm{SW}}=\mathrm{GND}$ to $\mathrm{V}_{\mathrm{CC}}$ |  |  |  |  |
|  |  | $\mathrm{I}_{\mathrm{SW}}=4 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V | - | - | 130 | $\Omega$ |
|  | $\mathrm{I}_{\mathrm{SW}}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | - | 55 | $\Omega$ |  |
|  |  | $\mathrm{I}_{\mathrm{SW}}=12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | - | 35 | $\Omega$ |
|  | $\mathrm{I}_{\mathrm{SW}}=24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | - | 25 | $\Omega$ |  |
|  | $\mathrm{I}_{\mathrm{SW}}=32 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | - | 20 | $\Omega$ |  |

[1] Typical values are measured at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ and nominal $\mathrm{V}_{\mathrm{CC}}$.

$\mathrm{R}_{\mathrm{ON}}=\mathrm{V}_{\mathrm{SW}} / \mathrm{I}_{\mathrm{SW}}$
Fig 7. Test circuit for measuring switch ON resistance

(1) $\mathrm{V}_{\mathrm{CC}}=1.8 \mathrm{~V}$
(2) $\mathrm{V}_{\mathrm{CC}}=2.5 \mathrm{~V}$
(3) $V_{C C}=2.7 \mathrm{~V}$
(4) $V_{C C}=3.3 \mathrm{~V}$
(5) $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$
(6) $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$

Fig 8. Typical switch ON resistance as a function of input voltage

(1) $\mathrm{T}_{\mathrm{amb}}=125^{\circ} \mathrm{C}$
(2) $\mathrm{T}_{\text {amb }}=85^{\circ} \mathrm{C}$
(3) $\mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$
(4) $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$
a. $\mathrm{V}_{\mathrm{CC}}=1.8 \mathrm{~V}$

(1) $\mathrm{T}_{\mathrm{amb}}=125^{\circ} \mathrm{C}$
(2) $\mathrm{T}_{\mathrm{amb}}=85^{\circ} \mathrm{C}$
(3) $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$
(4) $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$
c. $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$
(1) $\mathrm{T}_{\text {amb }}=125^{\circ} \mathrm{C}$
(2) $\mathrm{T}_{\mathrm{amb}}=85^{\circ} \mathrm{C}$
(3) $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$
(4) $\mathrm{T}_{\mathrm{amb}}=-40^{\circ} \mathrm{C}$

(1) $\mathrm{T}_{\mathrm{amb}}=125^{\circ} \mathrm{C}$
(2) $\mathrm{T}_{\text {amb }}=85^{\circ} \mathrm{C}$
(3) $\mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$
(4) $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$
b. $\mathrm{V}_{\mathrm{CC}}=2.5 \mathrm{~V}$

d. $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$

Fig 9. Switch ON resistance as a function of switch voltage

## 12. Dynamic characteristics

Table 10: Dynamic characteristics
At recommended operating conditions; voltages are referenced to GND (ground = 0 V ); test circuit Figure 12.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{T}_{\text {amb }}=-40{ }^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C} \underline{[1]}$ |  |  |  |  |  |  |
| tphL | HIGH-to-LOW propagation delay | see Figure 10 |  |  |  |  |
|  | A to Bn or Bn to A | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | - | - | 2 | ns |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ to 2.7 V | - | - | 1.2 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | - | 1.0 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | - | 0.8 | ns |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$ to 5.5 V | - | - | 0.6 | ns |
| $\mathrm{t}_{\text {PLH }}$ | LOW-to-HIGH propagation delay | see Figure 10 |  |  |  |  |
|  | A to Bn or Bn to A | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | - | - | 2 | ns |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ to 2.7 V | - | - | 1.2 | ns |
|  |  | $\mathrm{V}_{C C}=2.7 \mathrm{~V}$ | - | - | 1.0 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | - | 0.8 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | - | 0.6 | ns |
| $\mathrm{t}_{\text {on }}$ | turn-on time | see Figure 11 |  |  |  |  |
|  | S to A or Bn | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | 2.6 | 6.7 | 10.3 | ns |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ to 2.7 V | 1.9 | 4.1 | 6.4 | ns |
|  |  | $\mathrm{V}_{C C}=2.7 \mathrm{~V}$ | 1.9 | 4.0 | 5.5 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | 1.8 | 3.4 | 5.0 | ns |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$ to 5.5 V | 1.3 | 2.6 | 3.8 | ns |
|  | $\bar{E}$ to A or Bn | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | 1.9 | 4.0 | 7.3 | ns |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ to 2.7 V | 1.4 | 2.5 | 4.4 | ns |
|  |  | $\mathrm{V}_{C C}=2.7 \mathrm{~V}$ | 1.1 | 2.6 | 3.9 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | 1.2 | 2.2 | 3.8 | ns |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$ to 5.5 V | 1.0 | 1.7 | 2.6 | ns |
| $\mathrm{t}_{\text {off }}$ | turn-off time | see Figure 11 |  |  |  |  |
|  | S to A or Bn | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | 2.1 | 6.8 | 10.0 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | 1.4 | 3.7 | 6.1 | ns |
|  |  | $\mathrm{V}_{C C}=2.7 \mathrm{~V}$ | 1.4 | 4.9 | 6.2 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | 1.1 | 4.0 | 5.4 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | 1.0 | 2.9 | 3.8 | ns |
|  | $\bar{E}$ to A or Bn | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | 2.3 | 5.6 | 8.6 | ns |
|  |  | $\mathrm{V}_{\text {CC }}=2.3 \mathrm{~V}$ to 2.7 V | 1.2 | 3.2 | 4.8 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | 1.4 | 4.0 | 5.2 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | 2.0 | 3.7 | 5.0 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | 1.3 | 2.9 | 3.8 | ns |

Table 10: Dynamic characteristics ...continued At recommended operating conditions; voltages are referenced to GND (ground = 0 V ); test circuit Figure 12.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$ to +125 ${ }^{\circ} \mathrm{C}$ |  |  |  |  |  |  |
| $\mathrm{t}_{\text {PHL }}$ | HIGH-to-LOW propagation delay | see Figure 10 |  |  |  |  |
|  | A to Bn or Bn to A | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | - | - | 2.5 | ns |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ to 2.7 V | - | - | 1.5 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | - | 1.25 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | - | 1.0 | ns |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$ to 5.5 V | - | - | 0.8 | ns |
| tPLH | LOW-to-HIGH propagation delay | see Figure 10 |  |  |  |  |
|  | A to Bn or Bn to A | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | - | - | 2.5 | ns |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ to 2.7 V | - | - | 1.5 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | - | 1.25 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | - | - | 1.0 | ns |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$ to 5.5 V | - | - | 0.8 | ns |
| $\mathrm{t}_{\text {on }}$ | turn-on time | see Figure 11 |  |  |  |  |
|  | S to A or Bn | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | 2.6 | - | 12.9 | ns |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ to 2.7 V | 1.9 | - | 8.0 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | 1.8 | - | 7.0 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | 1.8 | - | 6.3 | ns |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$ to 5.5 V | 1.3 |  | 4.8 | ns |
|  | $\bar{E}$ to A or Bn | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | 1.9 | - | 9.2 | ns |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ to 2.7 V | 1.4 | - | 5.5 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | 1.1 | - | 4.9 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | 1.2 | - | 4.8 | ns |
|  |  | $\mathrm{V}_{\text {CC }}=4.5 \mathrm{~V}$ to 5.5 V | 1.0 | - | 3.3 | ns |
| $\mathrm{t}_{\text {off }}$ | turn-off time | see Figure 11 |  |  |  |  |
|  | S to A or Bn | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | 2.1 | - | 12.5 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | 1.4 | - | 7.7 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | 1.4 | - | 7.8 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | 1.1 | - | 6.8 | ns |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$ to 5.5 V | 1.0 |  | 4.8 | ns |
|  | $\bar{E}$ to A or Bn | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ to 1.95 V | 2.3 | - | 11.0 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | 1.2 | - | 6.0 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | 1.4 | - | 6.5 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ to 3.6 V | 2.0 | - | 6.3 | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | 1.3 | - | 4.8 | ns |

[1] Typical values are measured at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ and nominal $\mathrm{V}_{\mathrm{CC}}$.

## 13. Waveforms



Measurement points are given in Table 11.
Logic levels: $\mathrm{V}_{\mathrm{OL}}$ and $\mathrm{V}_{\mathrm{OH}}$ are typical output voltage drop that occur with the output load.
Fig 10. Input (Bn or A) to output (A or Bn) propagation delays


Table 11: Measurement points

| Supply voltage | Input | Output |  |  |
| :--- | :--- | :--- | :--- | :--- |
| $\mathbf{V}_{\mathbf{C C}}$ | $\mathbf{V}_{\mathbf{M}}$ | $\mathbf{V}_{\mathbf{M}}$ | $\mathbf{V}_{\mathbf{X}}$ | $\mathbf{V}_{\mathbf{Y}}$ |
| 1.65 V to 2.7 V | $0.5 \mathrm{~V}_{\mathrm{CC}}$ | $0.5 \mathrm{~V}_{\mathrm{CC}}$ | $\mathrm{V}_{\mathrm{OL}}+0.15 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OH}}-0.15 \mathrm{~V}$ |
| 2.7 V to 5.5 V | $0.5 \mathrm{~V}_{\mathrm{CC}}$ | $0.5 \mathrm{~V}_{\mathrm{CC}}$ | $\mathrm{V}_{\mathrm{OL}}+0.3 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OH}}-0.3 \mathrm{~V}$ |



Test data is given in Table 12.
Definitions test circuit:
$R_{T}=$ termination resistance (should be equal to output impedance $Z_{o}$ of the pulse generator).
$C_{L}=$ load capacitance (including jig and probe capacitance).
$R_{L}=$ load resistance.
$\mathrm{V}_{\mathrm{EXT}}=$ external voltage for measuring switching times.
Fig 12. Load circuitry for switching times

Table 12: Test data

| Supply voltage | Input |  | Load |  | $\mathrm{V}_{\text {EXT }}$ |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {cc }}$ | $\mathrm{V}_{\mathbf{I}}$ | $\mathrm{tr}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}$ | $\mathrm{C}_{\mathrm{L}}$ | $\mathbf{R}_{\mathrm{L}}$ | $\mathrm{t}_{\text {PLH, }}, \mathrm{t}_{\text {PHL }}$ | $t_{\text {on }}, t_{\text {off }}$ |  |
|  |  |  |  |  |  | HIGH to OFF OFF to HIGH | LOW to OFF OFF to LOW |
| 1.65 V to 1.95 V | $\mathrm{V}_{\mathrm{CC}}$ | $\leq 2.0 \mathrm{~ns}$ | 30 pF | $1 \mathrm{k} \Omega$ | open | GND | $2 \times V_{C C}$ |
| 2.3 V to 2.7 V | $\mathrm{V}_{C C}$ | $\leq 2.0 \mathrm{~ns}$ | 30 pF | $500 \Omega$ | open | GND | $2 \times V_{C C}$ |
| 2.7 V | $V_{C C}$ | $\leq 2.5 \mathrm{~ns}$ | 50 pF | $500 \Omega$ | open | GND | $2 \times V_{C C}$ |
| 3 V to 3.6 V | $\mathrm{V}_{\mathrm{CC}}$ | $\leq 2.5 \mathrm{~ns}$ | 50 pF | $500 \Omega$ | open | GND | $2 \times V_{C C}$ |
| 4.5 V to 5.5 V | $\mathrm{V}_{\mathrm{CC}}$ | $\leq 2.5 \mathrm{~ns}$ | 50 pF | $500 \Omega$ | open | GND | $2 \times V_{C C}$ |

## 14. Additional dynamic characteristics

Table 13: Additional dynamic characteristics
At recommended operating conditions; typical values measured at $T_{a m b}=25^{\circ} \mathrm{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| THD | total harmonic distortion | $\begin{aligned} & \mathrm{f}_{\mathrm{i}}=600 \mathrm{~Hz} \text { to } 20 \mathrm{kHz} ; \\ & \mathrm{R}_{\mathrm{L}}=600 \Omega ; \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} ; \\ & \mathrm{V}_{\mathrm{i}}=0.5 \mathrm{~V}(\mathrm{p}-\mathrm{p}) ; \text { see Figure } 13 \end{aligned}$ |  |  |  |  |
|  |  | $\mathrm{V}_{C C}=1.65 \mathrm{~V}$ | - | 0.260 | - | \% |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | 0.078 | - | \% |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | - | 0.078 | - | \% |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | 0.078 | - | \% |
| $\mathrm{f}_{(-3 \mathrm{~dB})}$ | $-3 d B$ frequency response | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega ; \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF} ; \\ & \text { see Figure } 14 \end{aligned}$ | [1] |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | 200 | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | 300 | - | MHz |
|  |  | $\mathrm{V}_{C C}=3.0 \mathrm{~V}$ | - | 300 | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | 300 | - | MHz |

Table 13: Additional dynamic characteristics ...continued At recommended operating conditions; typical values measured at $T_{a m b}=25^{\circ} \mathrm{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\alpha_{\text {OFF(t) }}$ | OFF-state feed-through attenuation | $\begin{aligned} & R_{\mathrm{L}}=50 \Omega ; \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF} ; \\ & \mathrm{f}_{\mathrm{i}}=10 \mathrm{MHz} ; \text { see Figure } 15 \end{aligned}$ | [2] |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | -42 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | -42 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | - | -40 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | -40 | - | dB |
| $\mathrm{V}_{\mathrm{ct} \text { (sw-sw) }}$ | crosstalkbetween switches | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega ; \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF} ; \\ & \mathrm{f}_{\mathrm{i}}=10 \mathrm{MHz} ; \text { see Figure } 16 \end{aligned}$ |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | -68 | - | dBV |
|  |  | $\mathrm{V}_{C C}=2.3 \mathrm{~V}$ | - | -70 | - | dBV |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | - | -70 | - | dBV |
|  |  | $\mathrm{V}_{C C}=4.5 \mathrm{~V}$ | - | -70 | - | dBV |
| $\mathrm{Q}_{\text {inj }}$ | charge injection | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=0.1 \mathrm{nF} ; \mathrm{V}_{\text {gen }}=0 \mathrm{~V} ; \\ & \mathrm{R}_{\mathrm{gen}}=0 \Omega ; \mathrm{f}_{\mathrm{i}}=1 \mathrm{MHz} ; \\ & \mathrm{R}_{\mathrm{L}}=1 \mathrm{M} \Omega ; \text { see Figure } 17 \end{aligned}$ | [3] |  |  |  |
|  |  | $\mathrm{V}_{C C}=1.8 \mathrm{~V}$ | - | < 0.003 | - | pC |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.5 \mathrm{~V}$ | - | 0.004 | - | pC |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$ | - | 0.0045 | - | pC |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | 0.0045 | - | pC |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | - | 0.0045 | - | pC |

[1] Adjust $f_{i}$ voltage to obtain 0 dBm level at output. Increase $\mathrm{f}_{\mathrm{i}}$ frequency until dB meter reads -3 dB .
[2] Adjust $f_{i}$ voltage to obtain 0 dBm level at input.
[3] Definition: $\mathrm{Q}_{\mathrm{inj}}=\Delta \mathrm{V}_{\mathrm{O}} \times \mathrm{C}_{\mathrm{L}}$. Guaranteed by design.


Fig 13. Test circuit for measuring total harmonic distortion


Fig 14. Test circuit for measuring the frequency response when switch is in ON-state


Fig 15. Test circuit for measuring feed-through attenuation when switch is in OFF-state


Fig 16. Test circuit for measuring crosstalk between switches

$\Delta \mathrm{V}_{\mathrm{O}}=$ output voltage variation
$\mathrm{R}_{\text {gen }}=$ generator resistance
$\mathrm{V}_{\text {gen }}=$ generator voltage
Fig 17. Test circuit for measuring charge injection

## 15. Package outline

| UNIT | $\mathbf{A}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| max. |  | $\mathbf{A}_{\mathbf{1}} \quad \mathbf{A}_{\mathbf{2}} \quad \mathbf{A}_{\mathbf{3}}$

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE <br> VERSION | REFERENCES |  |  |  | EUROPEAN <br> PROJECTION | ISSUE DATE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | JEITA |  |  |  |
| SOT765-1 |  | MO-187 |  |  | $02-06-07$ |  |

Fig 18. Package outline SOT765-1 (VSSOP8)


DIMENSIONS (mm are the original dimensions)

| UNIT | $\mathbf{A}^{(1)}$ <br> $\mathbf{m a x}$ | $\mathbf{A}_{\mathbf{1}}$ <br> $\max$ | $\mathbf{b}$ | $\mathbf{D}$ | $\mathbf{E}$ | $\mathbf{e}$ | $\mathbf{e}_{\mathbf{1}}$ | $\mathbf{L}$ | $\mathbf{L}_{\mathbf{1}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 0.5 | 0.04 | 0.25 <br> 0.17 | 2.0 <br> 1.9 | 1.05 <br> 0.95 | 0.6 | 0.5 | 0.35 <br> 0.27 | 0.40 <br> 0.32 |

Notes

1. Including plating thickness.
2. Can be visible in some manufacturing processes.

| OUTLINE <br> VERSION | REFERENCES |  |  |  | EUROPEAN <br> PROJECTION | ISSUE DATE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | JEITA |  |  |  |

Fig 19. Package outline SOT833-1 (XSON8)

## 16. Abbreviations

Table 14: Abbreviations

| Acronym | Description |
| :--- | :--- |
| CMOS | Complementary Metal Oxide Semiconductor |
| TTL | Transistor Transistor Logic |
| HBM | Human Body Model |
| ESD | ElectroStatic Discharge |
| MM | Machine Model |
| CDM | Charged Device Model |
| DUT | Device Under Test |

## 17. Revision history

Table 15: Revision history

| Document ID | Release date | Data sheet status | Change notice | Doc. number | Supersedes |
| :--- | :--- | :--- | :--- | :--- | :--- |
| 74LVC2G53_1 | 20060110 | Product data sheet | - | - | - |

## 18. Data sheet status

| Level | Data sheet status [1] | Product status [2] [3] | Definition |
| :---: | :---: | :---: | :---: |
| I | Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
| II | Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product. |
| III | Product data | Production | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). |

[1] Please consult the most recently issued data sheet before initiating or completing a design.
[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Short-form specification - The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition - Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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[^0]:    [1] To avoid drawing $\mathrm{V}_{\mathrm{CC}}$ current out of terminal A when switch current flows in terminal Bn , the voltage drop across the bidirectional switch must not exceed 0.4 V . If the switch current flows into terminal A , no $\mathrm{V}_{\mathrm{cc}}$ current will flow out of terminal Bn . In this case, there is no limit for the voltage drop across the switch.
    [2] Applies to control signal levels.

